

**Silicon NPN Power Transistors**

**2SC1847**

**DESCRIPTION**

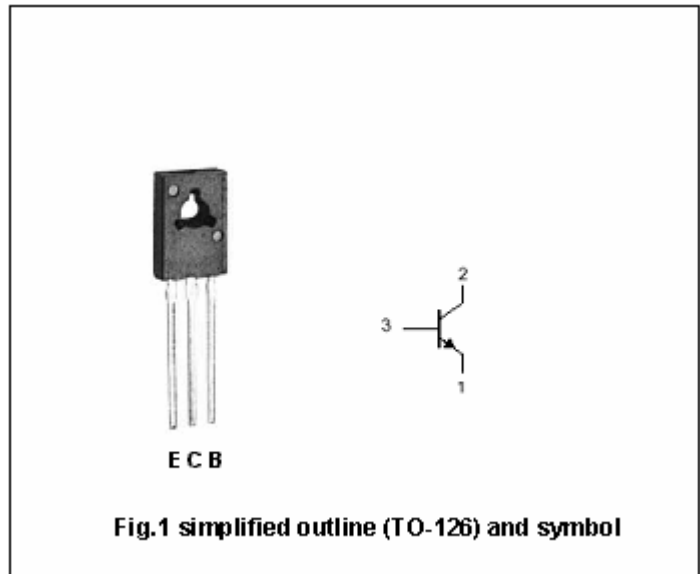
- With TO-126 package
- Complement to type 2SA886
- Low collector saturation

**APPLICATIONS**

- For medium output power amplification

**PINNING**

PIN	DESCRIPTION
1	Emitter
2	Collector;connected to mounting base
3	Base



**Absolute Maximun Ratings (Ta=25 )**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{CBO}$	Collector-base voltage	Open emitter	50	V
$V_{CEO}$	Collector-emitter voltage	Open base	40	V
$V_{EBO}$	Emitter-base voltage	Open collector	5	V
$I_C$	Collector current (DC)		1.5	A
$I_{CM}$	Collector current-peak		3	A
$P_C$	Collector power dissipation	$T_C=25$	1.2* <sup>1</sup>	W
			5* <sup>2</sup>	
$T_j$	Junction temperature		150	
$T_{stg}$	Storage temperature		-55~150	

Note) \*1: Without heat sink

\*2: With a 100 × 100 × 2 mm A1 heat sink

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## CHARACTERISTICS

T<sub>j</sub>=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> =2mA; I <sub>B</sub> =0	40			V
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =1mA; I <sub>E</sub> =0	50			V
V <sub>CEsat</sub>	Collector-emitter saturation voltage	I <sub>C</sub> =2A; I <sub>B</sub> =0.2A			1.0	V
V <sub>BEsat</sub>	Base-emitter saturation voltage	I <sub>C</sub> =2A; I <sub>B</sub> =0.2A			1.5	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =20V; I <sub>E</sub> =0			1	μA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> =10V; I <sub>B</sub> =0			100	μA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =5V; I <sub>C</sub> =0			10	μA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> =1A; V <sub>CE</sub> =5V	80		220	
C <sub>OB</sub>	Output capacitance	I <sub>E</sub> =0; V <sub>CB</sub> =20V; f=1MHz		35		pF
f <sub>T</sub>	Transition frequency	I <sub>C</sub> =0.5A; V <sub>CB</sub> =5V; f=200MHz		150		MHz

◆ h<sub>FE</sub> Classifications

Q	R
80-160	120-220

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PACKAGE OUTLINE

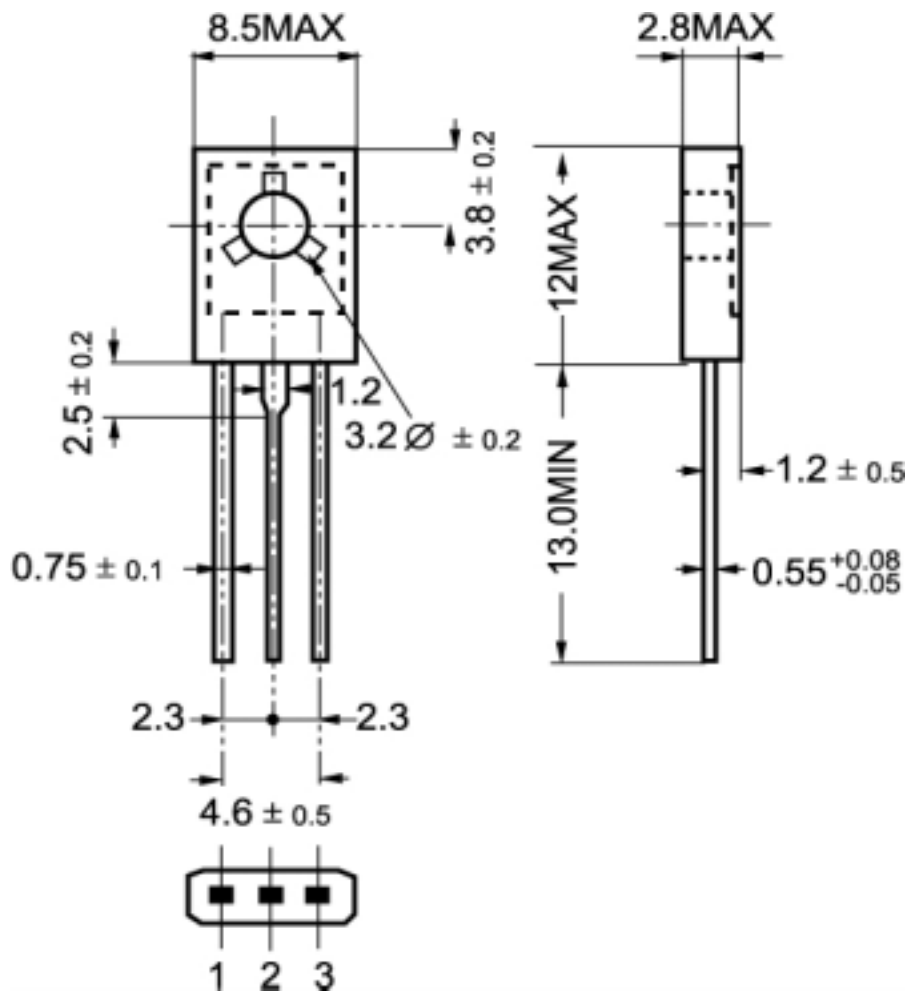


Fig.2 Outline dimensions

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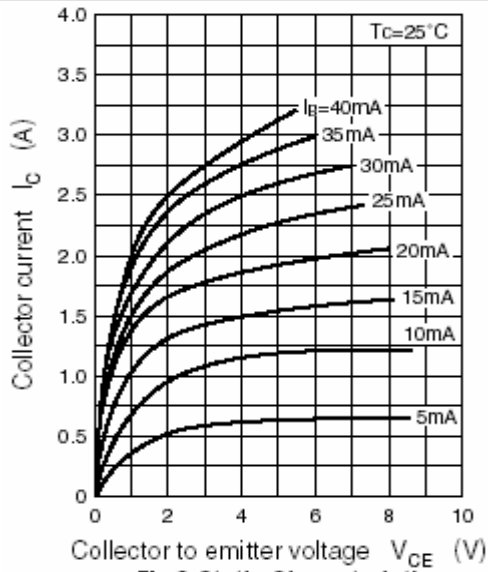


Fig.3 Static Characteristic

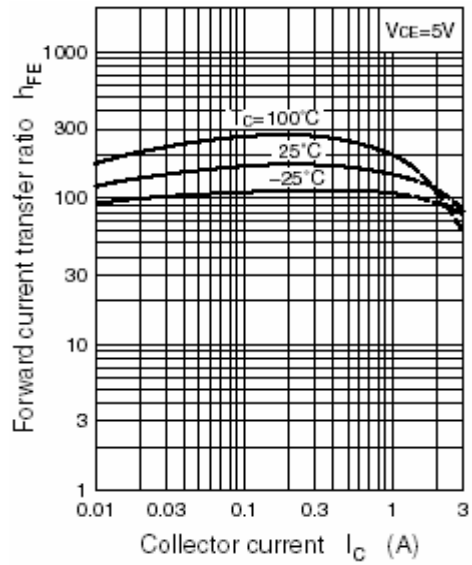


Fig.4 DC current Gain

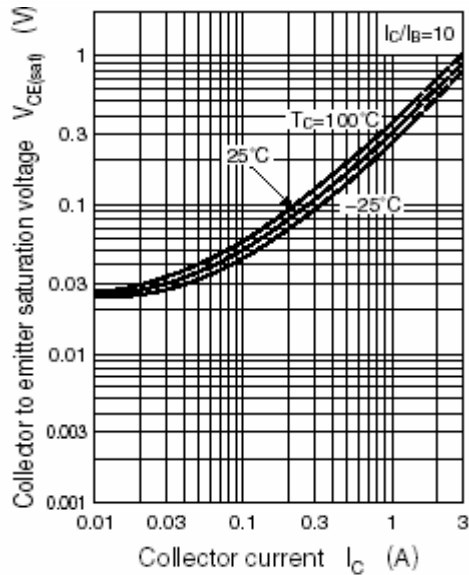


Fig.5 Collector-Emitter Saturation Voltage

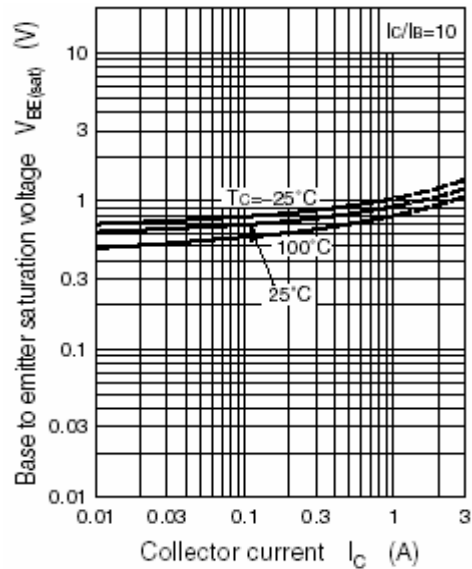


Fig.6 Base-Emitter Saturation Voltage

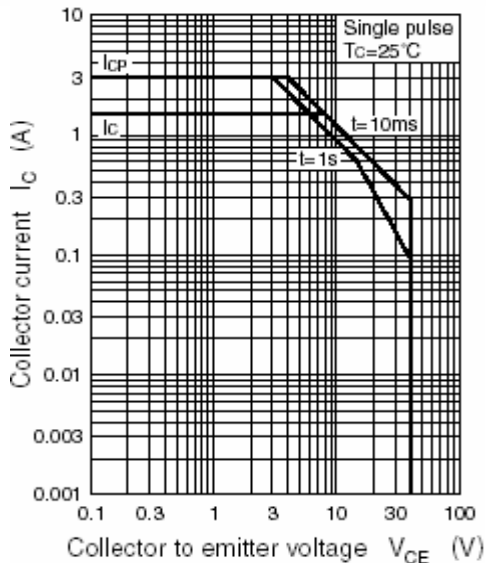


Fig.7 Safe Operating Area